

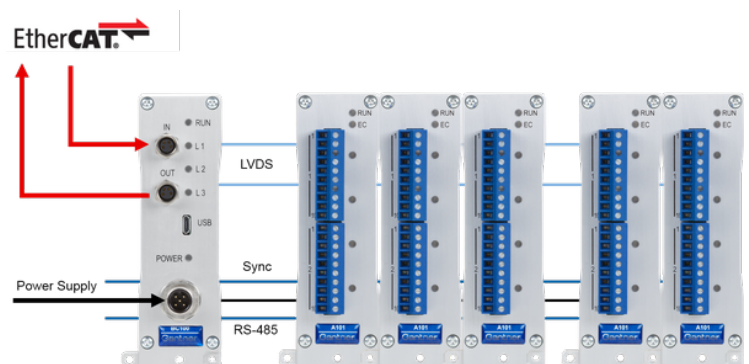
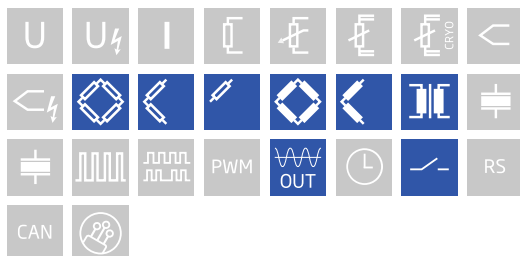
The Q.bloxx EC brings the high precision and performance of Q.bloxx to EtherCAT-based applications. Q.bloxx EC measurement modules possess integrated signal conditioning and arithmetic functions, packaged in environmentally secure (up to IP65), DIN Rail mountable enclosures that easily snap together for system expansion. With measurement speeds of up to 100 kHz per channel, short cycle times, and low jitter for accurate synchronization, Q.bloxx EC is the ideal solution for EtherCAT applications.

- CoE (CAN over EtherCAT) according to Modular Device Profil ETG.5001.1
- XFC technology for oversampling, oscilloscope function, cycle times 1 ms up to 0.1 ms, oversampling ≤ 100
- Configurable PDO Mapping to optimize the data throughput
- Module Configuration via SDO or FoE and alternative via configuration software
- Modular design for DIN Rail Mounting

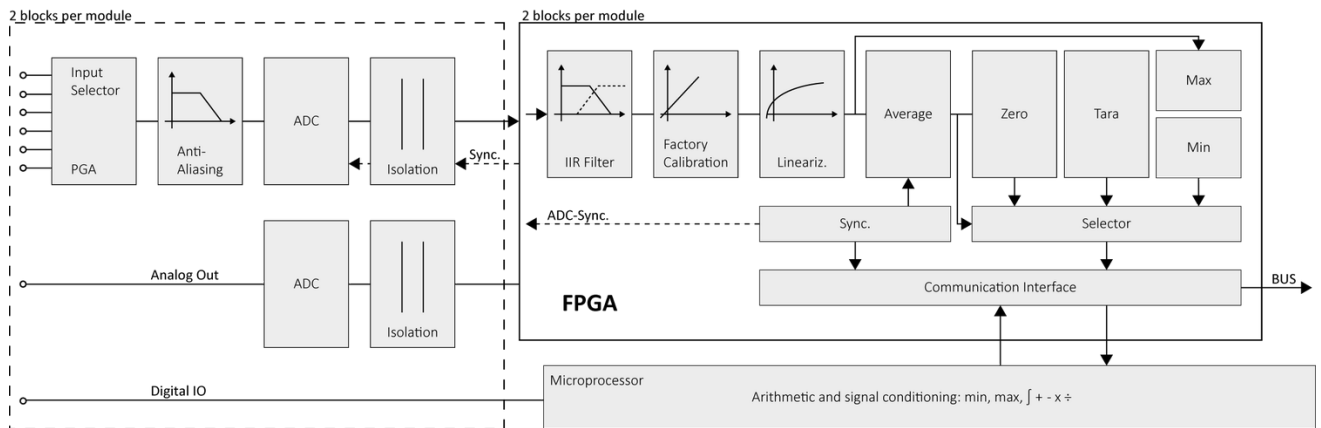


Key Features

- 2 galvanically isolated analog inputs channels
strain gage and inductive half and full bridges, LVDT, RVDT
quarter bridge with completion terminal
- DC and carrier frequency (CF) principle
2.5 and 5 VDC excitation, 2.5 and 5 VDCeff excitation carrier frequency,
600 Hz or 4.8 kHz configurable per channel
- 2 Analog output channels
 ± 10 VDC, 10 kHz update rate per channel
- High-accuracy digitization
24-bit ADC, 20 kHz sample rate per channel
- 4 digital I/Os
input: state, tare, memory reset, output: state, alarm, threshold
- Signal conditioning
linearization, filtering, average, scaling, min/max, RMS, arithmetic, alarm
- 3-Way galvanic isolation
500 VDC channel to channel, channel to power supply, and channel to bus



Block diagram



Technical Data

Analog Input

Channels	2
Accuracy	0.02 % typical 0.05 % in controlled environment ¹ 0.1 % in industrial area ²
Linearity error	0.02 % typical full-scale
Repeatability	0.01 % typical (within 24 hrs)
Input impedance	>10 MΩ
Isolation voltage	500 VDC channel to channel, to power supply, channel to bus ³

¹ according to EN 61326 2006: appendix B

² according to EN 61326 2006: appendix A

³ noise pulses up to 1000 VDC, continuous up to 250 VDC

Analog to Digital Conversion

Resolution	24-bit
Sample rate	10 kHz per channel
Modulation method	sigma-delta
Anti-aliasing filter	2 kHz, 3rd order (DC excitation) 1 kHz, 3rd order (4.8 kHz CF excitation) 100 Hz, 3rd order (600 Hz CF excitation)
Digital filters	Infinite impulse response (IIR), low-pass, high-pass, band-pass, band-stop, to 8th order Butterworth or Bessel, frequency range 0.1 Hz to 1 kHz in steps of 0.1 (adjustable via software)
Averaging	configurable or automatic according to the user-defined data rate

Analog Output

Channels	2		
Accuracy	0.02 % typical		
Voltage output	±10 VDC		
Allowable load resistance	> 2 kΩ		
Long-term drift	<1 mV / 24 hrs	<2.5 mV / 8000 hrs	
Temperature drift	<1 mV / 10 K Offset drift	<0.05 % / 10 K Gain drift	
Noise voltage	<2 mV at 10 Hz	<10 mV at 1 kHz	

Digital Input & Output

Channels	4 configurable I/Os		
Mode(s) of operation	status		
Logic voltage	< 2 VDC (Low) >10 VDC (High)		
Input type	PNP (current sinking)		
Input voltage	30 VDC max.		
Output voltage	10 to 30 VDC (external supply required)		
Contact	open drain p-channel MOSFET		
Load capacity	30 VDC / 100 mA (ohmic load)		

Strain Gage Measurement

Bridge configuration(s)	resistive full-bridge (4/6-wire) resistive half-bridge (3/5-wire) resistive quarter-bridge 120 Ω or 350 Ω (3-wire, with bridge completion terminal)			
Allowable sensor cable length	< 300 m (DC and 600 Hz CF excitation) < 100 m ¹ (4.8 kHz CF excitation)			
Shunt resistor	100 kΩ internal resistor			
Bridge excitation	2.5 - 5 VDC 2.5 - 5 V _{eff} (Carrier Frequency)			
Bridge excitation stability	< 0.01% / 24 hrs			
Bridge excitation drift	< 0.02% / 10 K			
	5 VDC	5 V_{eff} (CF)	2.5 VDC	2.5 V_{eff} (CF)
Allowable sensor resistance	> 300 Ω	> 300 Ω	> 100 Ω	> 100 Ω
Input range	±1.25 mV/V	±1.25 mV/V	±2.5 mV/V	±2.5 mV/V
	±2.5 mV/V	±2.5 mV/V	±5 mV/V	±5 mV/V
	±25 mV/V	±25 mV/V	±50 mV/V	±50 mV/V
	±50 mV/V	±50 mV/V	±100 mV/V	±100 mV/V
	±100 mV/V	±100 mV/V	±200 mV/V	±200 mV/V
	±200 mV/V	±200 mV/V	±400 mV/V	±400 mV/V
	±500 mV/V	±500 mV/V	±1000 mV/V	±1000 mV/V
Long-term stability	< 0.2 μV/V / 24 hrs (DC excitation) < 0.1 μV/V / 24 hrs (CF excitation)		< 2 μV/V / 8000 hrs (DC excitation) < 1 μV/V / 8000 hrs (CF excitation)	
Temperature drift (range 2.5 mV/V)	< 0.2 μV/V / 10 K Offset drift		< 0.05 % / 10 K Gain drift	
Signal-to-noise ratio	< 0.3 μV/V at 10 Hz		< 1 μV/V at 100 Hz	

¹ low capacity sensor cable is strongly recommended

LVDT/RVDT Measurement

Sensor connection	4- / 6-wire	
Sensor excitation (selectable)	5 V_{eff}	2.5 V_{eff}
Allowable sensor resistance	> 300 Ω	> 100 Ω
Input range	±1.25 mV/V	±2.5 mV/V
	±2.5 mV/V	±5 mV/V
	±25 mV/V	±50 mV/V
	±50 mV/V	±100 mV/V
	±100 mV/V	±200 mV/V
	±200 mV/V	±400 mV/V
	±500 mV/V	±1000 mV/V
Allowable sensor cable length	< 100 m ¹	
Long-term stability	< 0.1 μV/V / 24 hrs	< 1 μV/V / 8000 hrs
Temperature drift (range 2.5 mV/V)	< 0.2 μV/V / 10 K Offset drift	< 0.05 % / 10 K Gain drift
Signal-to-noise ratio	< 0.3 μV/V at 10 Hz	< 1 μV/V at 100 Hz

¹ low capacity sensor cable is strongly recommended

Digital to Analog Conversion

Resolution	16-bit
Update rate	10 kHz per channel
Settling time	3 μs

Communication Interface EtherCAT

Electrical standard	RS-485, 2-wire
Protocols	EtherCAT (LVDS)

Power Supply

Input voltage	10 to 30 VDC, overvoltage and overcurrent protection
Power consumption	2.5 W (approx.)
Input voltage influence	< 0.001 % / V

Environmental Specifications

Electromagnetic compatibility (EMC)	according to IEC 61000-4 and EN 55011
Operating temperature	-20°C to +60°C
Storage temperature	-40°C to +85°C
Relative humidity	5 - 95 % at 50°C (non-condensing)

Remarks

Validity of all listed specifications are subject to a warm-up period of at least 45 minutes

Specifications subject to change without notice

Mechanical information

Material	Aluminum and ABS
Measurements (W x H x D)	35.6 x 118.8 x 124 mm
Weight	approx. 400 g

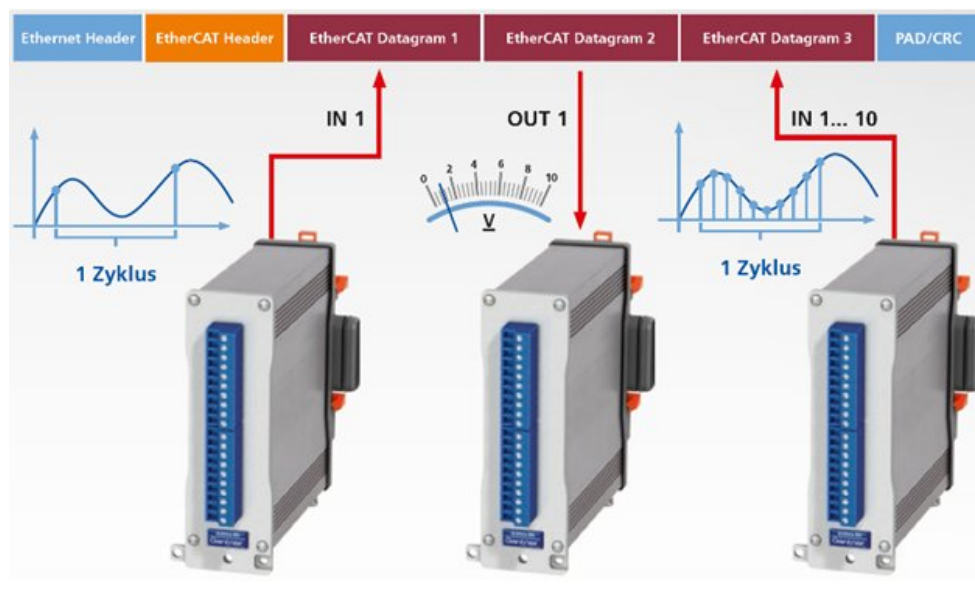
Oversampling

EtherCAT also enables transmitting of very high data rates at low bus cycle by over sampling. In this case, a higher number of values of one channel per PDO transmitted so as to reduce protocol overhead.

Example: bus cycle 1 kHz, 100 times over sampling

= > 100 values are transferred per bus cycle

= > effective sample rate 100 kHz



Ordering Information

Article number	528229
Accessories	Terminal B4/120-A106, article number 894387
	Terminal B4/350-A106, article number 894488

Gantner Instruments

Austria | Germany | France | Sweden | India | USA | China | Singapore
Montafonerstraße 4 · A-6780 Schruns · T +43 55 56 · 77 463-0

office@gantner-instruments.com
www.gantner-instruments.com